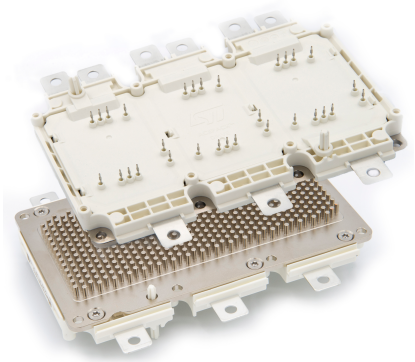
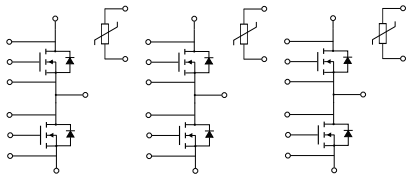
ADP360120W3

Datasheet

Automotive-grade ACEPACK DRIVE power module, sixpack topology 1200 V, 2.55 mΩ typ. SiC MOSFET gen.3 based



ACEPACK DRIVE



Features

- AQG 324 qualified
- 1200 V blocking voltage
- 2.55 mΩ of typical $R_{DS(on)}$
- Maximum operating junction temperature T_J = 175 °C
- Very low switching energy
- Low inductive compact design for an higher power density
- Si_3N_4 AMB substrate to improve thermal performance
- SiC Power MOSFET chip sintered to substrate for improved lifetime
- 4.2 kV DC 1 s insulation
- Directly liquid cooled base plate with pin-fins
- Three integrated NTC temperature sensors

Application

- Main inverter (electric traction)

Description

The ACEPACK DRIVE is a compact sixpack module optimized for hybrid and electric vehicles traction inverter. This power module features switches based on silicon carbide Power MOSFET 3rd generation, are characterized by very low $R_{DS(on)}$, very limited switching losses and outstanding performances in synchronous rectification working mode. This will ensure superb efficiency in final application, saving battery recharging cycles.

A copper base plate with pin-fin base structure make direct fluid cooling available for this power module minimizing thermal resistance.

A dedicated pin-out has been developed to get the best switching performances and press-fit pins will ensure optimal connection with driving board.

Product status link
ADP360120W3

Product summary	
Order code	ADP360120W3
Marking	ADP360120W3
Package	ACEPACK DRIVE
Leads type	Press-fit
Packing	Tray

1 Electrical ratings

Table 1. Absolute maximum ratings of each switch

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	1200	V
V_{GS}	Gate-source voltage	-10 to 22	V
	Gate-source voltage (recommended operating values)	-5 to 18	
I_D (1)	Continuous drain current at T_F = 75 °C (refer to T_J max = 175 °C, V_{GS} = 18 V)	379	A
I_{DM} (2)	Repetitive peak drain current	800	A
P_{TOT}	Total power dissipation at T_F = 75 °C (refer to T_J max = 175 °C, V_{GS} = 18 V)	704	W
T_J	Operative junction temperature range under switching conditions	-40 to 175 (3)	°C

1. *Specified by design, not tested in production.*
2. *Pulse width limited by maximum junction temperature.*
3. *Maximum baseplate temperature has to be always limited to 125 °C.*

Table 2. Thermal data of each switch

Symbol	Parameter	Value	Unit
R_{thJF} (1)	Thermal resistance, junction-to-fluid (flow rate = 10 LPM, T_F = 75 °C, single switch)	0.129	°C/W

1. *Simulated value considering 50% water/ 50% ethylene glycol cooling fluid. Refer to TN1412 "ACEPACK DRIVE assembly instructions" for water jacket design.*

2 Electrical characteristics

T_J = 25 °C, unless otherwise specified.

Table 3. Electrical characteristics of each switch

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$R_{DS(on)}$ (1)	Static drain-source on-resistance	V_{GS} = 18 V, I_D = 360 A		2.55	3.45	mΩ
		V_{GS} = 18 V, I_D = 360 A, T_J = 175 °C		4.25		
		V_{GS} = 18 V, I_D = -360 A		2.4		
		V_{GS} = 18 V, I_D = -360 A, T_J = 175 °C		4.2		
$V_{GS(th)}$	Gate threshold voltage	V_{DS} = V_{GS}, I_D = 40 mA	1.9	3.1	4.4	V
I_{DSS}	Zero gate voltage drain current	V_{GS} = 0 V, V_{DS} = 1200 V			100	µA
		V_{GS} = 0 V, V_{DS} = 1200 V, T_J = 150 °C (2)			2	mA
I_{GSS}	Gate-body leakage current	V_{DS} = 0 V, V_{GS} = -10 to 22 V			2	µA
C_{iss}	Input capacitance	V_{DS} = 800 V, f = 1 MHz, V_{GS} = 0 V		28.07		nF
C_{oss}	Output capacitance			1.07		
C_{rss}	Reverse transfer capacitance			0.09		
Q_g	Total gate charge	V_{DS} = 800 V, I_D = 360 A, V_{GS} = -5 V to 18 V		944		nC
Q_{gs}	Gate-source charge			323		
Q_{gd}	Gate-drain charge			302		

1. *$R_{DS(on)}$ is referred to switch level.*
2. *Specified by design, not tested in production.*

Table 4. Switching energy of each switch

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
E_{on} (1)	Turn-on switching energy	V_{DD} = 800 V, V_{GS} = -5 to 18 V, di/dt_{on} = 4.3 A/ns, R_{G-ON} = 10 Ω, R_{G-OFF} = 6.8 Ω, I_D = 360 A	-	24.7	-	mJ
		V_{DD} = 800 V, V_{GS} = -5 to 18 V, di/dt_{on} = 5.1 A/ns, R_{G-ON} = 10 Ω, R_{G-OFF} = 6.8 Ω, I_D = 360 A, T_J = 175 °C	-	21.3	-	
E_{off}	Turn-off switching energy	V_{DD} = 800 V, V_{GS} = -5 to 18 V, dv/dt_{off} = 8.3 V/ns, R_{G-ON}= 10 Ω, R_{G-OFF} = 6.8 Ω, I_D = 360 A	-	18.1	-	mJ
		V_{DD} = 800 V, V_{GS} = -5 to 18 V, dv/dt_{off} = 9.4 V/ns, R_{G-ON} = 10 Ω, R_{G-OFF} = 6.8 Ω, I_D = 360 A, T_J = 175 °C	-	18.7	-	

1. *Using active Miller clamp circuit.*

Table 5. Source-drain diode characteristics of each switch

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{SD}	Forward on voltage drop	V_{GS} = -5 V, I_{SD} = 360 A	-	4.3	-	V
t_{rr}	Reverse recovery time	V_{DD} = 800 V, V_{GS} = -5 to 18 V, R_{G-ON} = 10 Ω, R_{G-OFF} = 6.8 Ω, di/dt_{on} = 4.3 A/ns, I_{SD} = 360 A	-	33.4	-	ns
Q_{rr}	Reverse recovery charge		-	1.97	-	µC
I_{RRM}	Reverse recovery current		-	102	-	A
E_{rec}	Reverse recovery energy		-	0.36	-	mJ
t_{rr}	Reverse recovery time	V_{DD} = 800 V, V_{GS} = -5 to 18 V, R_{G-ON} = 10 Ω, R_{G-OFF} = 6.8 Ω, di/dt_{on} = 5.1 A/ns, I_{SD} = 360 A, T_J = 175 °C	-	57	-	ns
Q_{rr}	Reverse recovery charge		-	5.5	-	µC
I_{RRM}	Reverse recovery current		-	164	-	A
E_{rec}	Reverse recovery energy		-	1.54	-	mJ

Note: Values are calculated taking in account an active Miller clamp circuit.

3 NTC

Table 6. Absolute maximum ratings for NTC temperature sensor, considered as stand-alone

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
R_{25}	Resistance	T = 25 °C		5.0		kΩ
R_{100}	Resistance	T = 100 °C		493		Ω
ΔR/R	Deviation of R_{100}		-5		+5	%
$B_{25/50}$	B-constant			3375		K
$B_{25/80}$				3411		

4 ACEPACK DRIVE power module details

Table 7. Ratings for module

Symbol	Parameter		Value	Unit
V_{ISO}	Isolation voltage (f = 0 Hz, t = 1 s)		4.2	kV
	Internal isulation (class 1, IEC 61140)		Si_3N_4	
	Baseplate module material		Ni plated, Cu baseplate	
d_{creep}	Creepage distance	Terminal to heat sink	9.0	mm
		Terminal to terminal	9.0	
d_{clear}	Clearance distance	Terminal to heat sink	4.5	mm
		Terminal to terminal	4.5	
CTI	Comparative tracking index		>200	
L_s	Typical stray inductance drain to source module loop		10	nH
R_s	Typical module lead resistance, terminals to chip		0.5	mΩ
T_{stg}	Storage temperature range		-40 to 125	°C

5 Electrical characteristics (curves)

Figure 1. Typical output characteristics (T_J = -40°C)

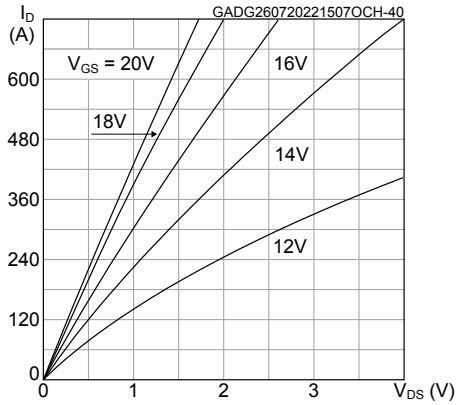


Figure 2. Typical output characteristics (T_J = 25°C)

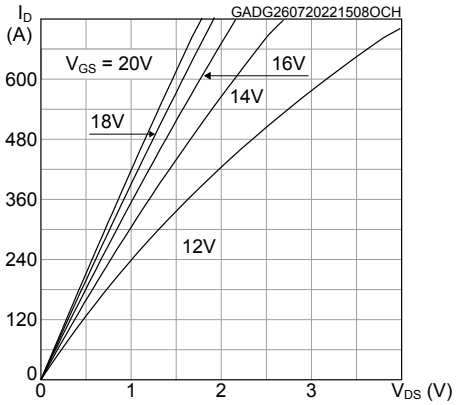


Figure 3. Typical output characteristics (T_J = 175 °C)

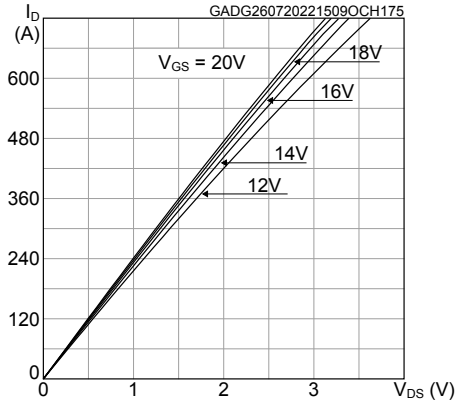


Figure 4. Typical reverse conduction characteristics (T_J = -40 °C)

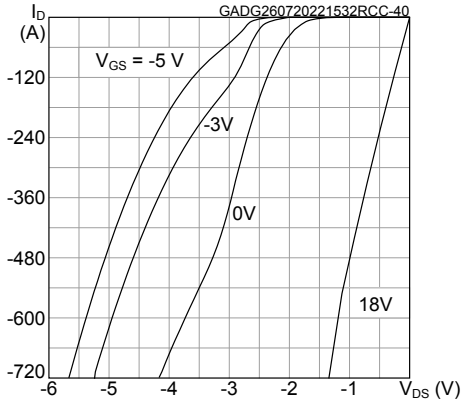


Figure 5. Typical reverse conduction characteristics (T_J= 25°C)

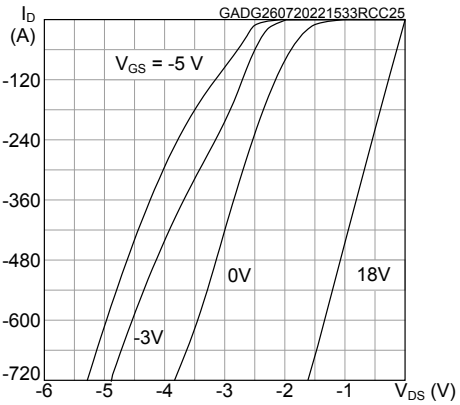


Figure 6. Typical reverse conduction characteristics (T_J = 175°C)

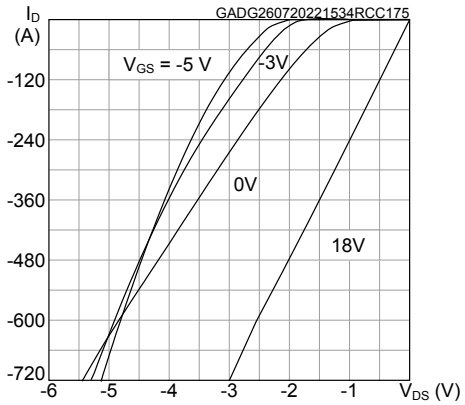


Figure 7. Typical transfer characteristics

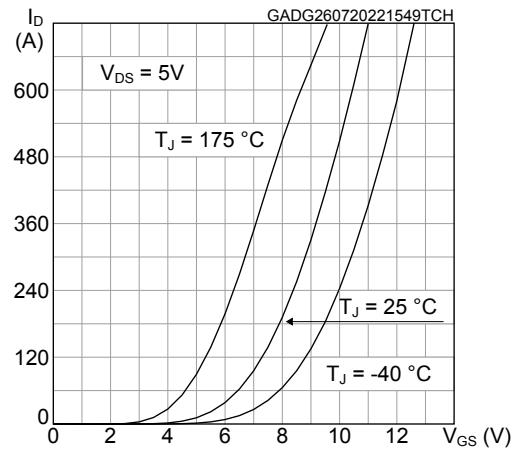


Figure 8. Normalized breakdown voltage vs temperature

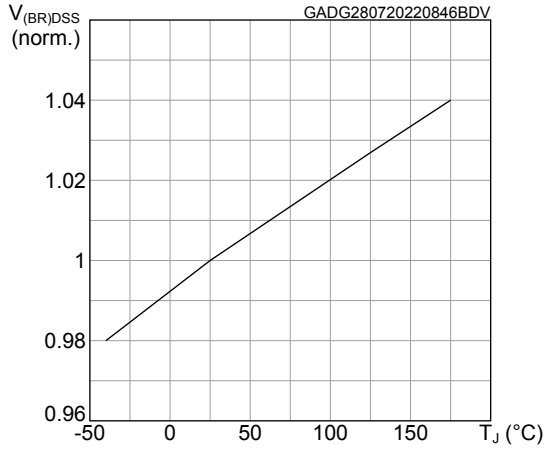


Figure 9. Typical switching energy vs drain current

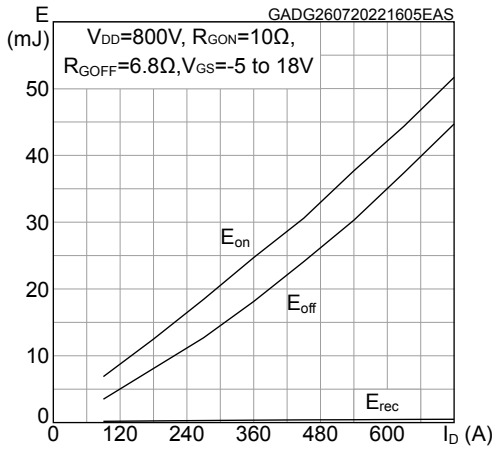


Figure 10. Typical switching energy vs gate resistance

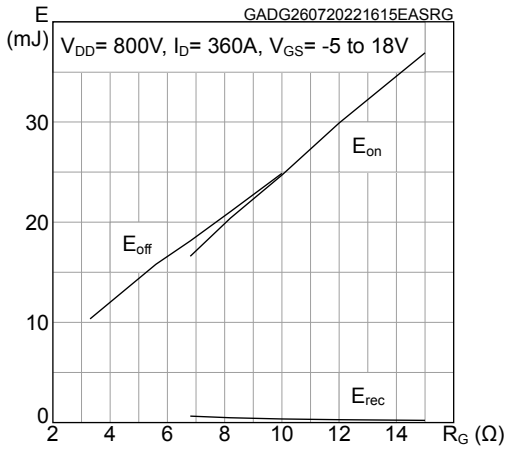


Figure 11. Typical switching energy vs temperature

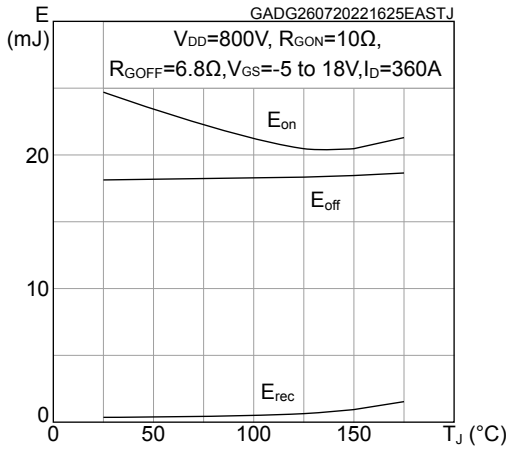


Figure 12. Typical switching energy vs bus voltage

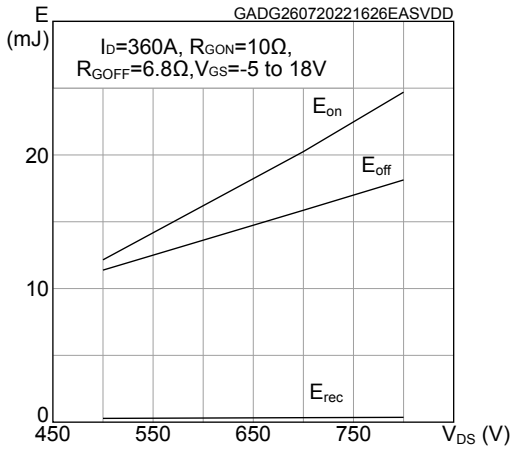


Figure 13. Typical capacitance characteristics

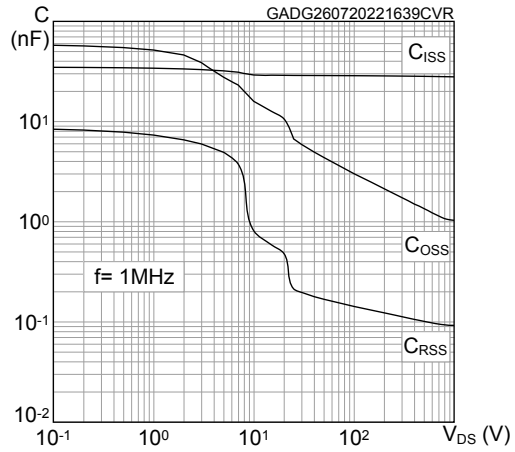


Figure 14. Typical gate charge characteristics

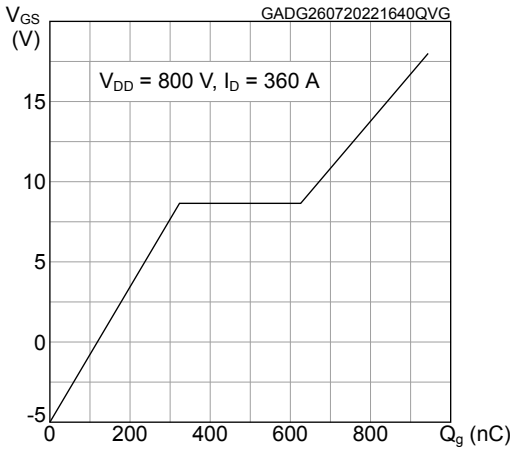


Figure 15. Typical transient thermal impedance

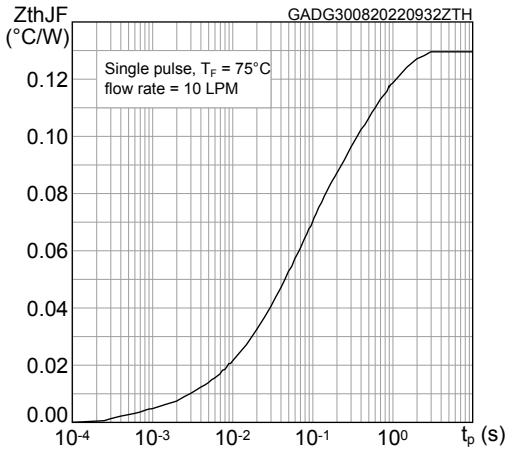


Figure 16. Typical thermal resistance vs flow rate

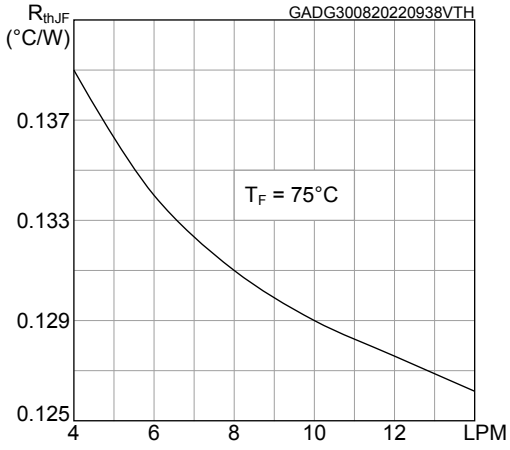
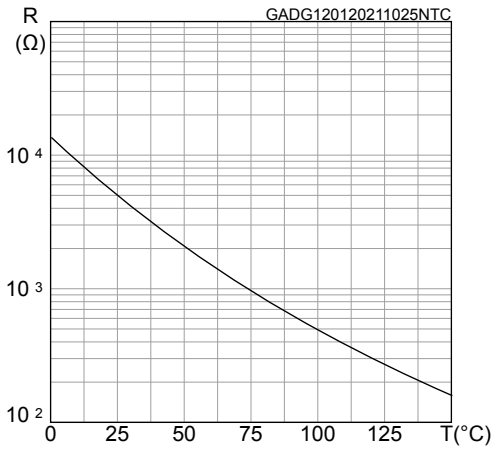


Figure 17. Typical NTC resistance vs temperature



6 Topology, pin description and positioning

Figure 18. **Topology, pin description and positioning**

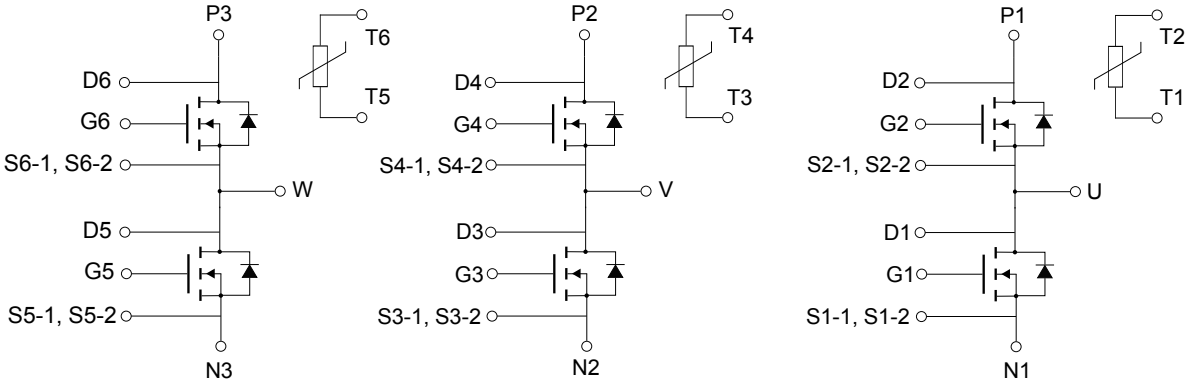
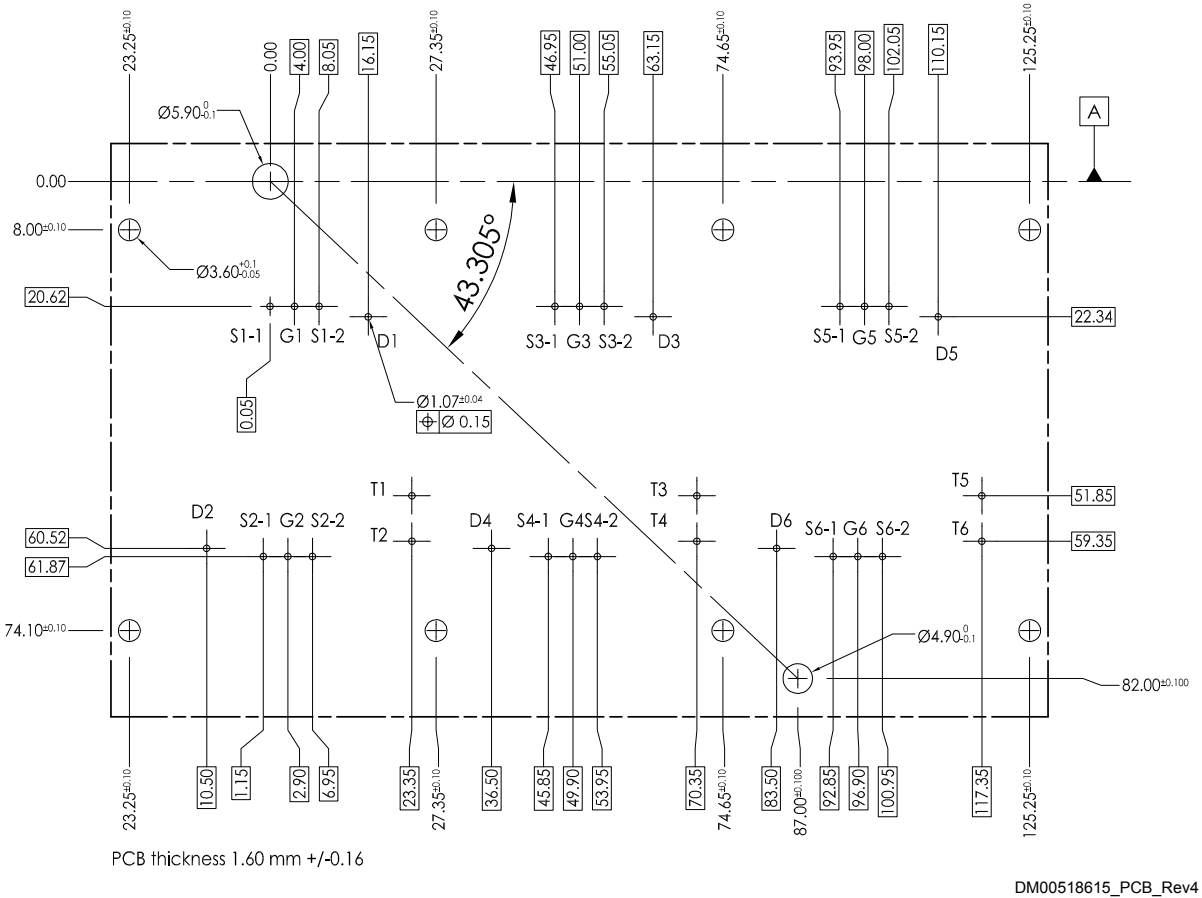


Figure 19. **ACEPACK DRIVE PCB drawing (dimensions are in mm.)**

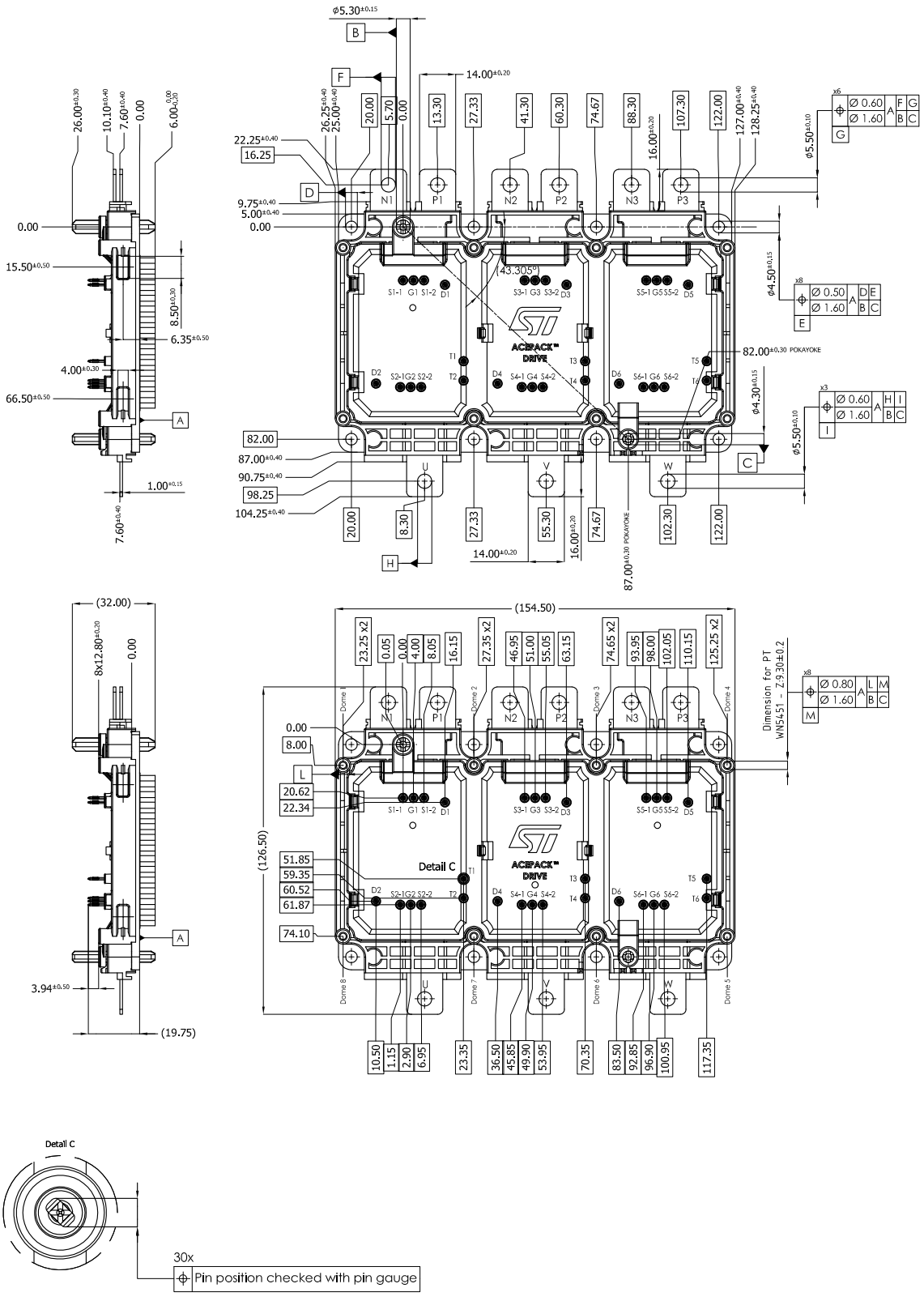


7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

7.1 ACEPACK DRIVE package information

Figure 20. **ACEPACK DRIVE short tab package outline (dimensions are in mm.)**



DM00518615_Rev5

Revision history

Table 8. **Document revision history**

Date	Revision	Changes
06-Sep-2021	1	First release.
02-Aug-2022	2	Removed *Section 1.1 Inverter switch*, inserted and updated *Table 1. Absolute maximum ratings of each switch*, added *Table 2. Thermal data of each switch* under the *Section 1 Electrical ratings*. Inserted and updated *Table 3. Electrical characteristics of each switch*, added *Table 4. Switching energy of each switch* and updated *Table 5. Source-drain diode characteristics of each switch* under *Section 2 Electrical characteristics*. Updated *Table 6. Absolute maximum ratings for NTC temperature sensor, considered as stand-alone*. Updated *Figure 20. ACEPACK DRIVE short tab package outline (dimensions are in mm.)*. Inserted *Section 5 Electrical characteristics (curves)*. Minor text changes.
06-Sep-2022	3	Updated Section 1 Electrical ratings, Section 5 Electrical characteristics (curves) and Section 7.1 ACEPACK DRIVE package information. Minor text changes.

Contents